

RFVC1801C

CONNECTORIZED MODULE WIDEBAND MMIC VCO WITH BUFFER AMPLIFIER, 5 GHz TO 10 GHz

Package: Module, 3 Connectors, 22.86mmx22.86mmx13.97mm

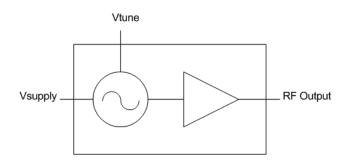


Features

- 5GHz to 10GHz VCO
- 5V Operation, 52 mA
- +3.0dBm Typical Output Power
- -72dBc/Hz @ 10kHz
- -96dBc/Hz @ 100kHz

Applications

- Military Radar, Communications, ECM/IED
- Satcomm Communication Modems
- Test Instrumentation
- Industrial/Medical Equipment



Functional Block Diagram

Product Description

RFMD's RFVC1801C wideband Voltage Controlled Oscillator is an InGaP HBT MMIC with integrated VCO core and RF output buffer. The part operates from a single +5V supply for circuit bias and 0V to +18V V_{TUNE} for frequency control. The RFVC1801C offers low phase noise and low power consumption.

Ordering Information

RFVC1801C Connectorized VCO

Optimum Technology Matching® Applied

	GaAs HBT	☐ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEM
	GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ BiFET HBT
V	InGaP HBT	☐ SiGe HBT	☐ Si BJT	☐ LDMOS

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RFVC1801C



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{CC})	5.5	V
V _{TUNE}	0 to +20	V
Storage Temperature	-55 to +125	°C
Operating Temperature	-40 to +85	°C
ESD Rating – Human Body Model (HBM)	Class0	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

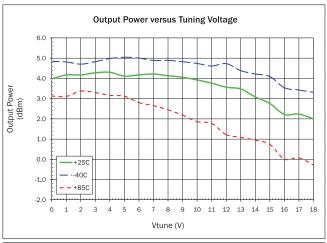
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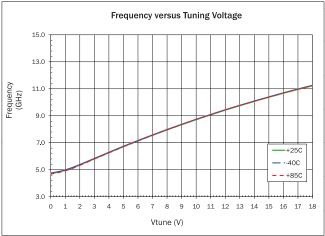
Parameter	Specification		Unit	Condition	
raidilletei	Min.	Тур.	Max.	Unit	Condition
Frequency					
Frequency Range	5.0		10.0	GHz	
Supply Voltage (V _S)	4.75	5.00	5.25	V	Recommended operating range.
Supply Current	40	52	70	mA	
Tuning Voltage (V _{TUNE})	0		18	V	
Tuning Sensitivity		390		MHz/V	
Output Power		3		dBm	
Output Phase Noise at 10kHz		-72		dBc/Hz	
Output Phase Noise at 100kHz		-96		dBc/Hz	
2nd Harmonic		-20		dBc	
Frequency Pushing		18		MHz/V	
Frequency Pulling (2:1 VSWR)		5		MHz pp	
RF Output Return Loss		-10		dB	
Frequency Drift Rate		-0.7		MHz/°C	
V _{TUNE} port input capacitance		7		pF	

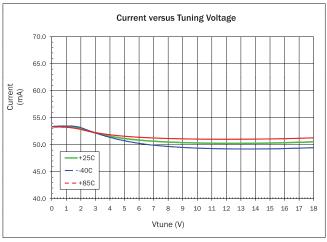
Test Conditions: $V_S=5V$, Freq=5GHz to 10GHz, T=25 °C unless noted otherwise



RFVC1801C Thermal Performance versus Tuning Voltage



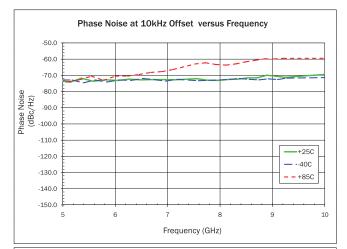


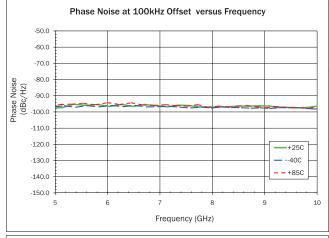


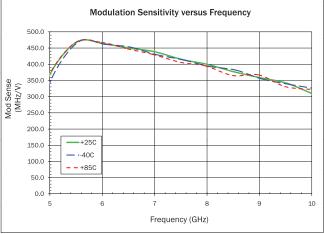
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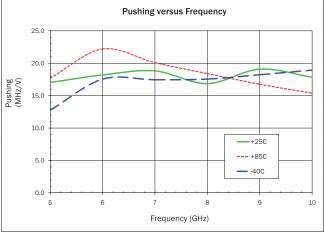


RFVC1801C Thermal Performance versus Frequency



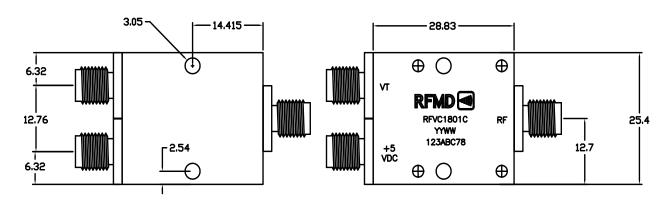


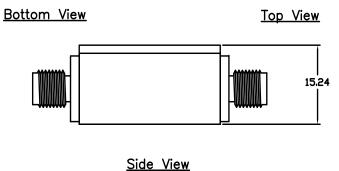






Pin Out and Package Drawing (mm)





Date Code - YYWW (Year and Week)
Trace Code - 123ABC78